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# 2SD2592L, 2SD2592S

Silicon NPN Triple Diffused  
Low Frequency Amplifier

# HITACHI

1st. Edition  
December 1997  
Target Specification

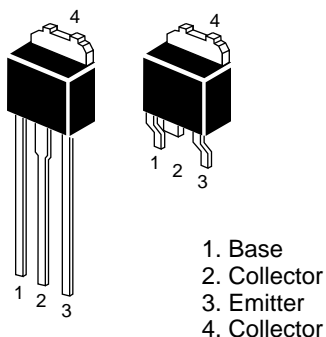
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## Features

- High voltage :  $V_{(BR)CEO} = 300V$  min.

## Outline

DPAK



## 2SD2592L, 2SD2592S

### Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to Base voltage	$V_{CBO}$	300	V
Collector to Emitter voltage	$V_{CEO}$	300	V
Emitter to Base voltage	$V_{EBO}$	5	V
Collector current	$I_C$	0.15	A
Collector peak current	$I_{C(peak)}$	0.6	A
Collector power dissipation	$P_C$ <sup>Note1</sup>	10	W
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

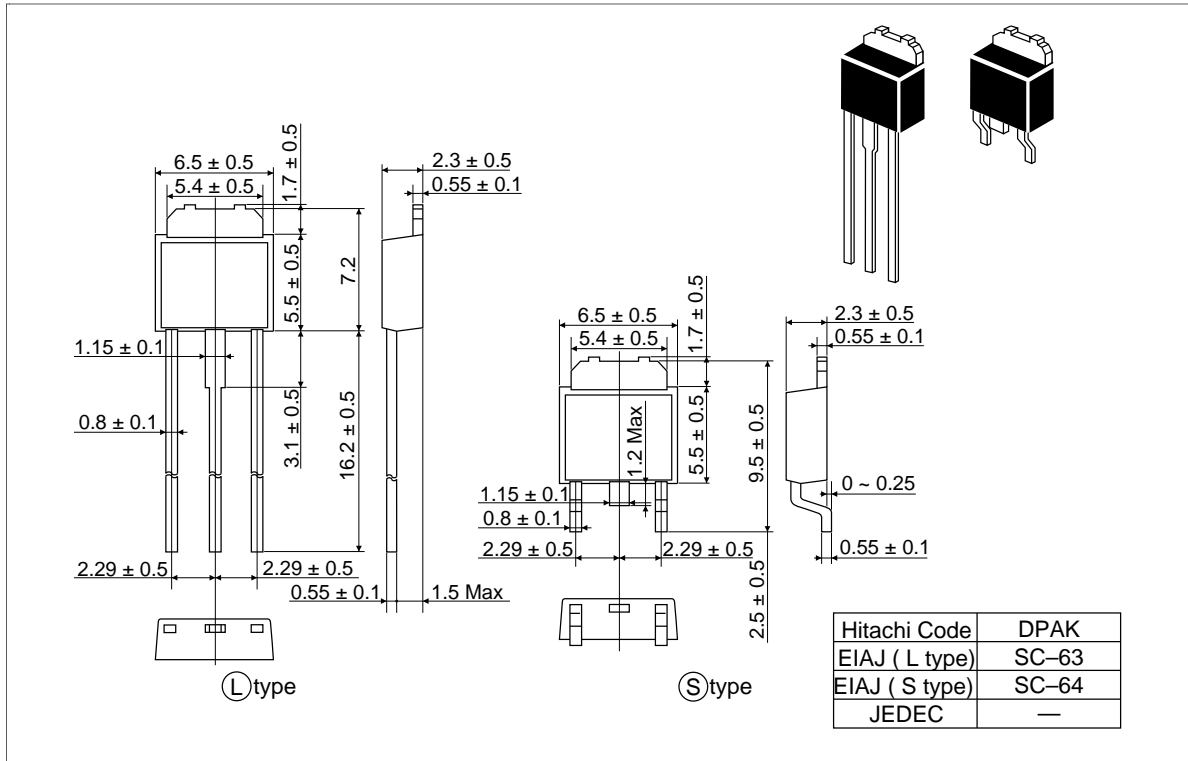
Note: 1. Value at  $T_C = 25^\circ\text{C}$

### Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	300	—	—	V	$I_C = 1\text{mA}$ , $R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	—	V	$I_E = 10\text{mA}$ , $I_C = 0$
Collector cutoff current	$I_{CBO}$	—	—	10	$\mu\text{A}$	$V_{CB} = 300\text{V}$ , $I_E = 0$
Emitter cutoff current	$I_{EBO}$	—	—	10	$\mu\text{A}$	$V_{EB} = 4\text{V}$ , $I_C = 0$
DC current transfer ratio	$h_{FE1}$	60	—	200		$V_{CE} = 1.5\text{V}$ , $I_C = 20\text{mA}$
DC current transfer ratio	$h_{FE2}$	60	—	—		$V_{CE} = 5\text{V}$ , $I_C = 100\text{mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	1.0		$I_C = 100\text{mA}$ , $I_B = 5\text{mA}$
Base to emitter saturation voltage	$V_{BE(sat)}$	—	—	1.5		$I_C = 100\text{mA}$ , $I_B = 5\text{mA}$
Gain bandwidth product	$f_T$	—	16	—	MHz	$V_{CE} = 1.5\text{A}$ , $I_C = 20\text{mA}$

Package Dimensions

Unit: mm



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